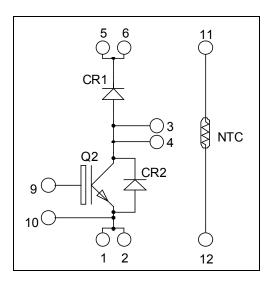
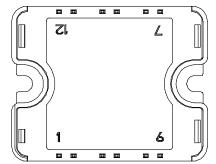


Boost chopper High speed IGBT 5 Power Module

$$V_{CES} = 650V$$

 $I_{C} = 100A$ @ $Tc = 25^{\circ}C$





Pins 1/2; 3/4; 5/6 must be shorted together

Application

- AC and DC motor control
- Switched Mode Power Supplies
- **Power Factor Correction**

Features

- High speed IGBT 5
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Low leakage current
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

All ratings @ $T_i = 25$ °C unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		650	V
ī	Continuous Callastan Comment	$\Gamma_{\rm C} = 25^{\circ}{\rm C}$	100	
I_{C}	Continuous Collector Current $T_{C} = 80^{\circ}C$		60	Α
I_{CM}	Pulsed Collector Current	$\Gamma_{\rm C} = 25^{\circ}{\rm C}$	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation		250	W

😘 🚓 UTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

1 - 6



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				100	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $T_{j} = 25^{\circ}C$ $T_{j} = 150^{\circ}C$	$T_j = 25$ °C		1.65	2.2	V
$V_{CE(sat)}$			$T_{j} = 150^{\circ}C$		1.9		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$		3.3	4.0	4.7	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				240	nA

Dynamic Characteristics

Symbol	Characteristic	Test Condition	ns	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$		6000		
C_{oes}	Output Capacitance				100		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			22		
Q_{G}	Gate charge	$V_{GE} = 15V, I_{C}$ $V_{CE} = 520V$	$V_{GE} = 15V, I_{C} = 100A$ $V_{CE} = 520V$		240		nC
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (25°C)		21		
T_{r}	Rise Time	$V_{GE} = 15V$			15		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400 \text{V}$ $I_{\text{C}} = 50 \text{A}$			180		
T_{f}	Fall Time	$R_G = 2\Omega$			18		
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (150°C)		20		ns
T_{r}	Rise Time	$V_{GE} = 15V$			15		
$T_{d(off)}$	Turn-off Delay Time		$V_{Bus} = 400V$ $I_C = 50A$ $R_G = 2\Omega$		205		
T_{f}	Fall Time				26		
Eon	Turn on Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 150$ °C		1.5		mJ
E_{off}	Turn off Energy	$I_{C} = 50A$ $R_{G} = 2\Omega$	$T_j = 150$ °C		0.6		1113
R_{Gint}	Integrated gate resistor				2.5		Ω
R_{thJC}	Junction to Case Thermal Resistance					0.6	°C/W

diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Typ	Max	Unit		
V_{RRM}	Peak Repetitive Reverse Voltage					650	V	
I_{RM}	Reverse Leakage Current	$V_R=650V$				100	μΑ	
I_F	DC Forward Current		$Tc = 25^{\circ}C$		100		A	
V	Diode Forward Voltage	$I_{\rm F} = 100A$	$T_i = 25^{\circ}C$		1.6	2.2	V	
V_{F}		$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.65		V	
t_{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		46		ns	
·rr	Reverse Recovery Time $I_F = 50A$ $V_R = 400V$	$T_{\rm j} = 150^{\circ}{\rm C}$		62		115		
	Daviana Bassiani Changa	everse Recovery Charge $ \frac{V_R - 400V}{\text{di/dt} = 3000\text{A}/\mu\text{s}} $	$d_i/d_t = 3000 \text{ A/Hz}$ $T_i = 25^\circ$	$T_j = 25$ °C	25°C	1		C
Q_{rr}	Reverse Recovery Charge		$T_j = 150$ °C		2		μC	
R_{thJC}	Junction to Case Thermal Resistance					0.7	°C/W	



Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

Symbol	naracteristic		Min	Тур	Max	Unit
R ₂₅	sistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		$T_{\rm C} = 100^{\circ}{\rm C}$		4		%

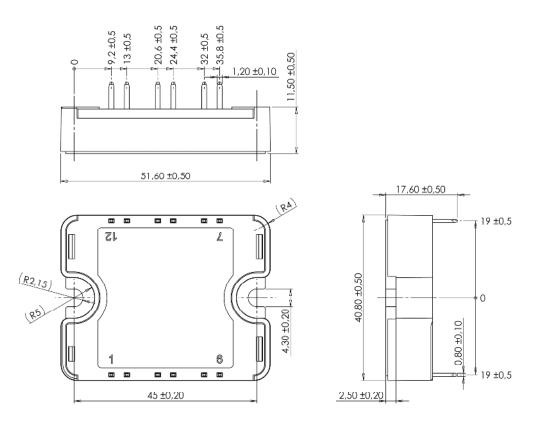
$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
T_{J}	Operating junction temperature range			-40	175	
T_{JOP}	Recommended junction temperature under sy	witching condit	ions	-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight	•			80	g

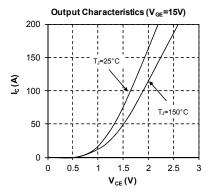
Package outline (dimensions in mm)

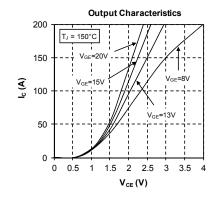


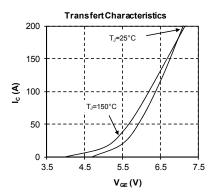
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

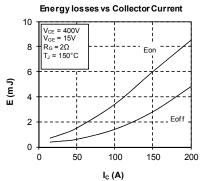


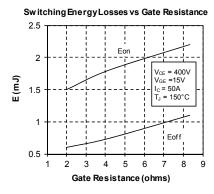
Typical performance curve

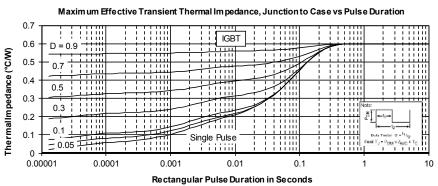






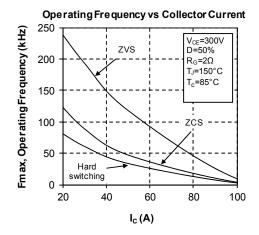


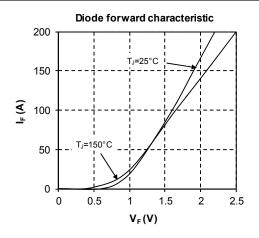


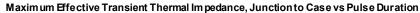


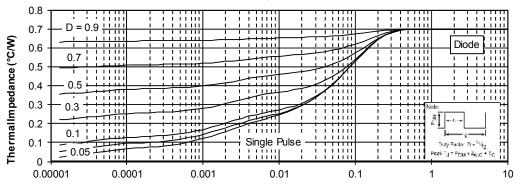


Power Matters."









 $Re\,ctangular\,Pulse\,Duration\,in\,Se\,conds$



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